

isc Silicon NPN Power Transistor

BDY58S

DESCRIPTION

- Collector-Emitter Sustaining Voltage-
: $V_{CEO(SUS)} = 125V(\text{Min})$
- High Power Dissipation
- Low Collector Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

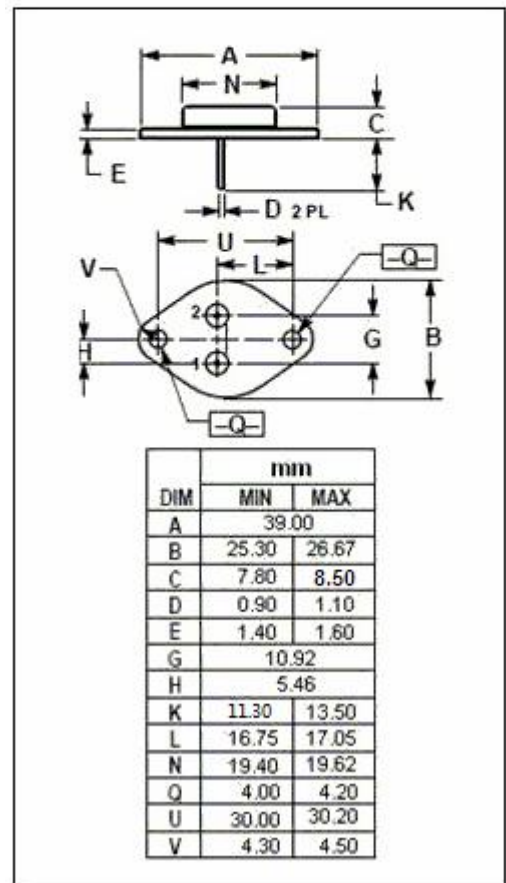
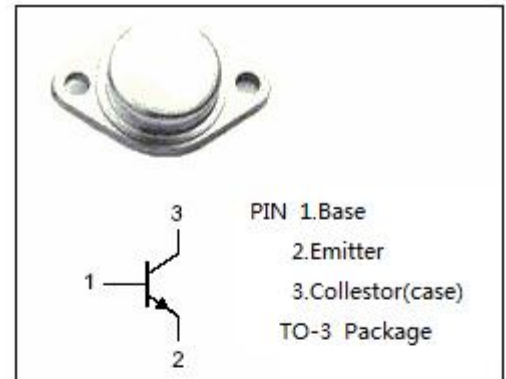
- LF signal power amplification.
- High current fast switching

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector- Base Voltage	160	V
V_{CEO}	Collector-Emitter Voltage	125	V
V_{EBO}	Emitter-Base Voltage	10	V
I_C	Collector Current-Continuous	25	A
I_B	Base Current-Continuous	6	A
P_C	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	175	W
T_J	Junction Temperature	200	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	1.0	$^\circ\text{C/W}$



isc Silicon NPN Power Transistor**BDY58S****ELECTRICAL CHARACTERISTICS**T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEQ(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA ; I _B = 0	125			V
V _{(BR)CBO}	Collector- Base Breakdown Voltage	I _C = 1mA ; I _E = 0	160			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA ; I _C = 0	10			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10A; I _B = 1A			1.4	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 120V; I _E = 0			0.5	mA
I _{CER}	Collector Cutoff Current	V _{CE} = 80V; R _{BE} = 10 Ω V _{CE} = 80V; R _{BE} = 10 Ω ; T _C =100°C			0.5 10	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 10V; I _C = 0			0.5	mA
h _{FE-1}	DC Current Gain	I _C = 10A ; V _{CE} = 4V	20		60	
h _{FE-2}	DC Current Gain	I _C = 20A ; V _{CE} = 4V		15		
f _T	Current-Gain—Bandwidth Product	I _C = 1A ; V _{CE} = 15V; f= 10MHz	7			MHz

Switching Times

t _{on}	Turn-On Time	I _C = 15A , I _B = 1.5A,			1.0	μ s
t _{off}	Turn-Off Time	I _C = 15A , I _{B1} = -I _{B2} = 1.5A,			2.0	μ s

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.